



迈拓电子  
MAITUO ELECTRONIC

## DTA114EM Series Digital Transistor (Built-In Resistors)

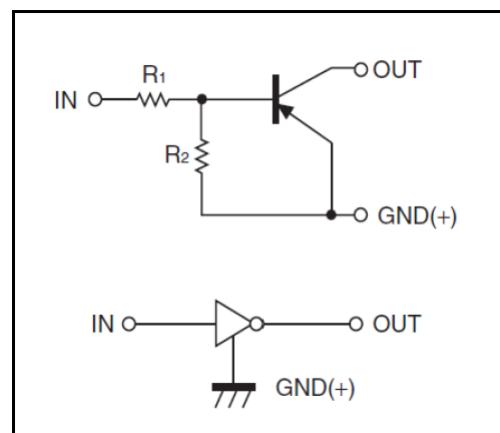
Digital transistor (PNP)

### FEATURES

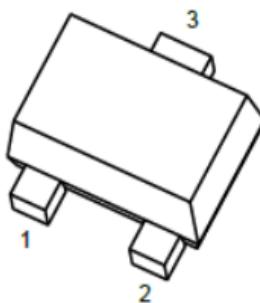
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easier
- AEC-Q101 qualified

Marking : 14

### PIN CONNECTIONS AND MARKING



DTA114EM



SOT-723

1. IN
2. GND
3. OUT



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### MAXIMUM RATINGS ( $T_j = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value						Unit
		M	E	UA	CA	KA	SA	
Supply voltage	V <sub>CC</sub>	-50						V
Input voltage	V <sub>IN</sub>	-40 ~ 10						V
Output current	I <sub>O</sub> <sup>1)</sup>	-50						mA
Peak collector current	I <sub>CM</sub> <sup>1)</sup>	-100						mA
Maximum power dissipation	P <sub>D</sub> <sup>1)</sup>	100	150	200	200	200	300	mW
Operating junction and storage temperature range	T <sub>j</sub> , T <sub>stg</sub>	-55 ~ 150						°C

### ELECTRICAL CHARACTERISTICS ( $T_j = 25^\circ\text{C}$ unless otherwise specified)

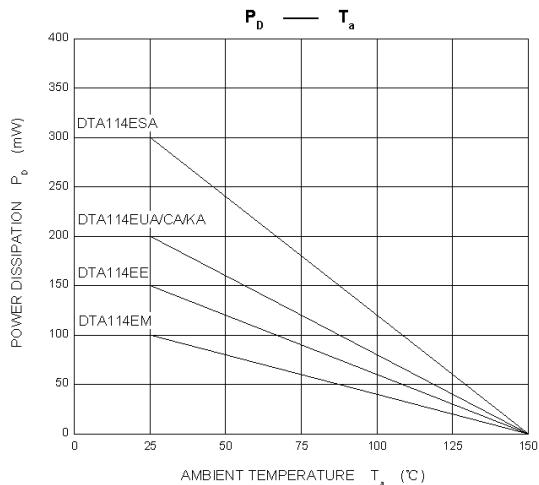
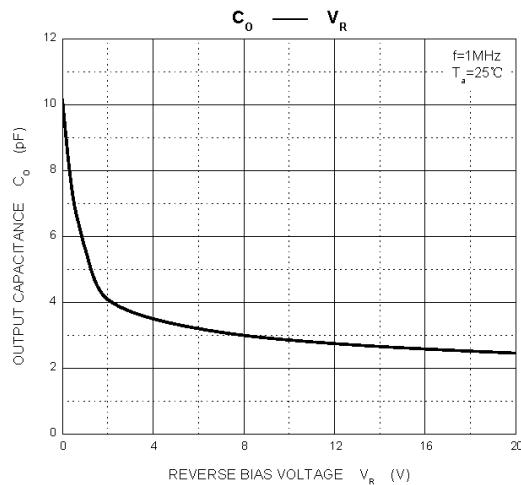
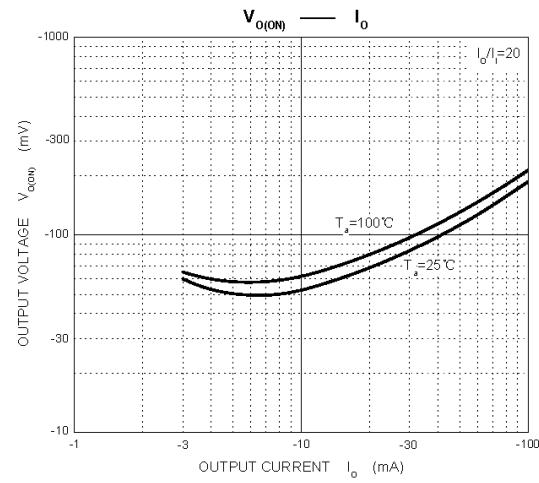
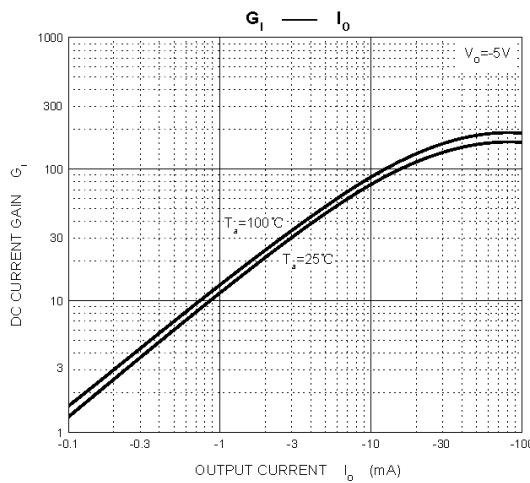
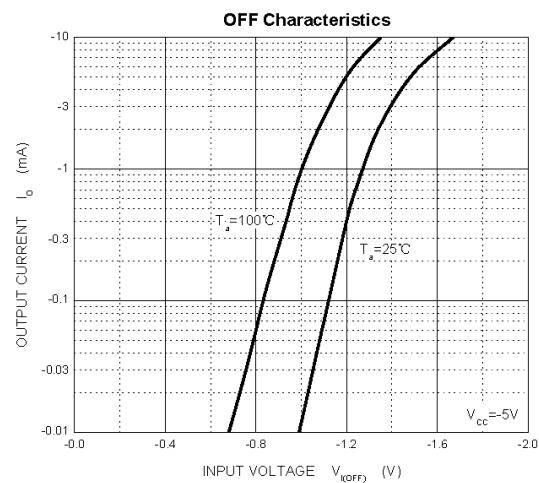
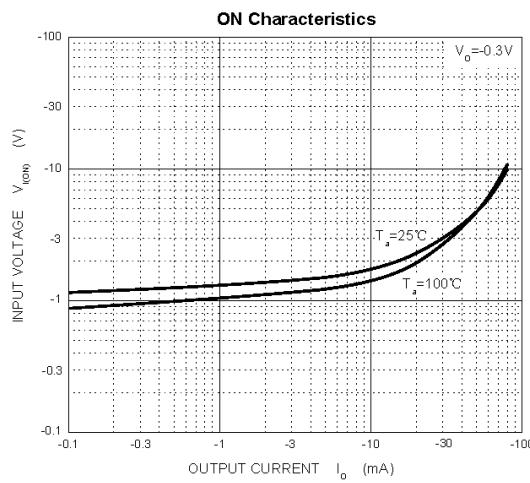
Parameter	Symbol	Test condition	Min	Typ	Max	Unit
Input voltage	V <sub>I(off)</sub>	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA	-0.5	-	-	V
	V <sub>I(on)</sub>	V <sub>O</sub> = -0.3V, I <sub>O</sub> = -10mA	-	-	-3	
Output voltage	V <sub>O(on)</sub>	I <sub>O</sub> /I <sub>I</sub> = -10mA/-0.5mA	-	-	-0.3	V
Input current	I <sub>I</sub>	V <sub>I</sub> = -5V	-	-	-0.88	mA
Output current	I <sub>O(off)</sub>	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0V	-	-	-0.5	μA
DC current gain	G <sub>I</sub>	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA	30	-	-	-
Input resistance	R <sub>I</sub>		7	10	13	kΩ
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>		0.8	1	1.2	
Transition frequency	f <sub>T</sub>	V <sub>O</sub> = -10V, I <sub>O</sub> = -5mA, f = 100MHz	-	250	-	MHz

1) Maximum allowed temperature T<sub>j</sub> = 25°C.



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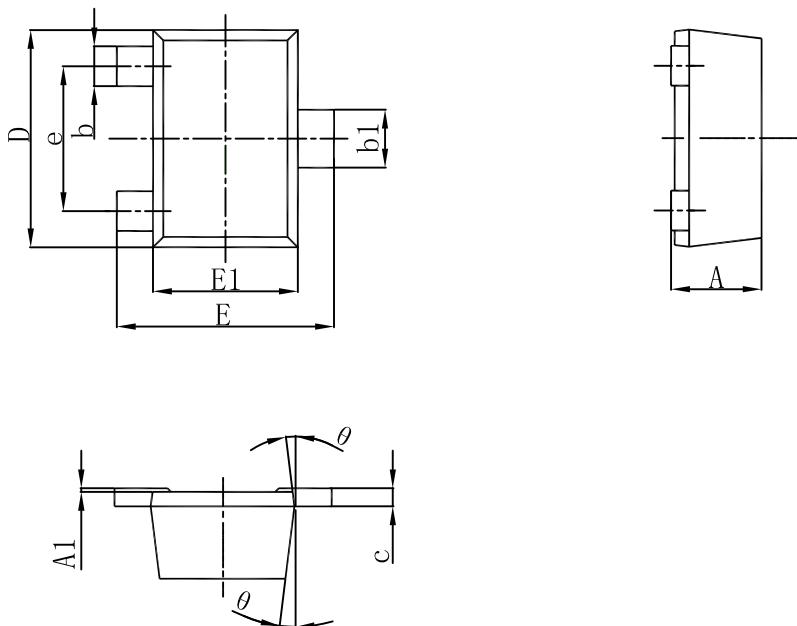
## TYPICAL CHARACTERISTICS





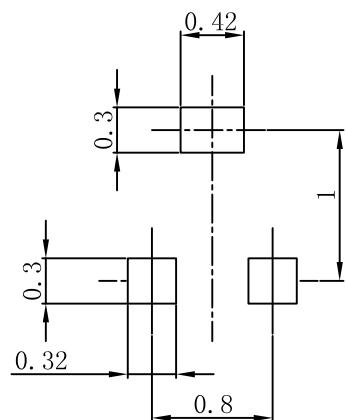
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### SOT-723 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.450	0.550	0.018	0.022
A1	0.000	0.050	0.000	0.002
b	0.170	0.270	0.007	0.011
b1	0.270	0.370	0.011	0.015
c	0.080	0.150	0.003	0.006
D	1.150	1.250	0.045	0.049
E	1.150	1.250	0.045	0.049
E1	0.750	0.850	0.030	0.033
e	0.800TYP.		0.031TYP.	
θ	7° REF.		7° REF.	

### SOT-723 Suggested Pad Layout



#### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.